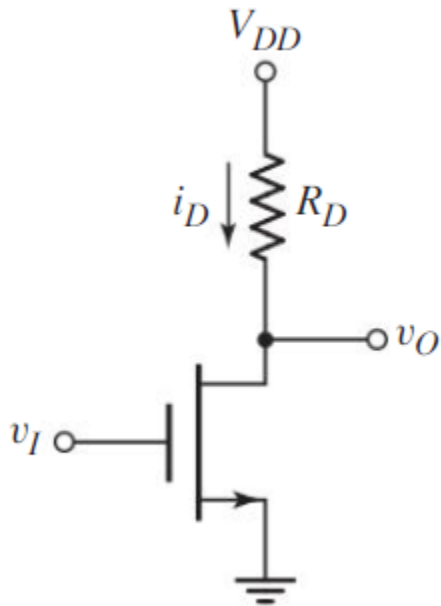


NMOS Inverter

Exercise 1



For the NMOS Inverter shown- $V_{DD} = 6\text{ V}$, $V_{TN} = 0.3\text{ V}$
 $V_{in}(\text{high}) = 6\text{ V}$, $V_{in}(\text{low}) = 0\text{ V}$, $K_n = 0.2\text{ A/V}^2$

- If the **average** power dissipation is 1.1654 W , find the value of R_D .
- Find the drain current for maximum power dissipation of the inverter.
- Find the transition point.
- Find the power dissipation at the transition point.
- If the output voltage is 4.2 V , find the input voltage at the gate.

a) 1.07 V

b) 1.896 W

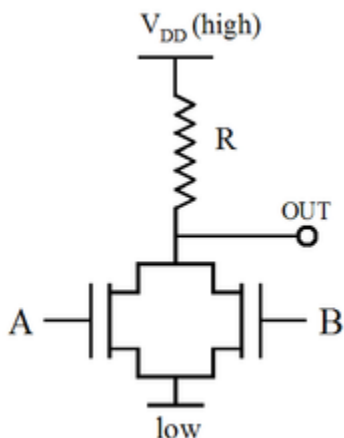
c) 1.56 V

d) 0.388 W

e) 15 V

NMOS NOR Gate

Exercise 2



For the given NMOS NOR gate- $V_{in}(\text{High}) = V_{DD} = 5\text{ V}$
 $V_{in}(\text{Low}) = 0\text{ V}$, $V_{TN_A} = 0.25\text{ V}$, $V_{TN_B} = 0.3\text{ V}$, $K_{n_A} = 0.4\text{ A/V}^2$
 $K_{n_B} = 0.5\text{ A/V}^2$, $R = 20\text{ }\Omega$

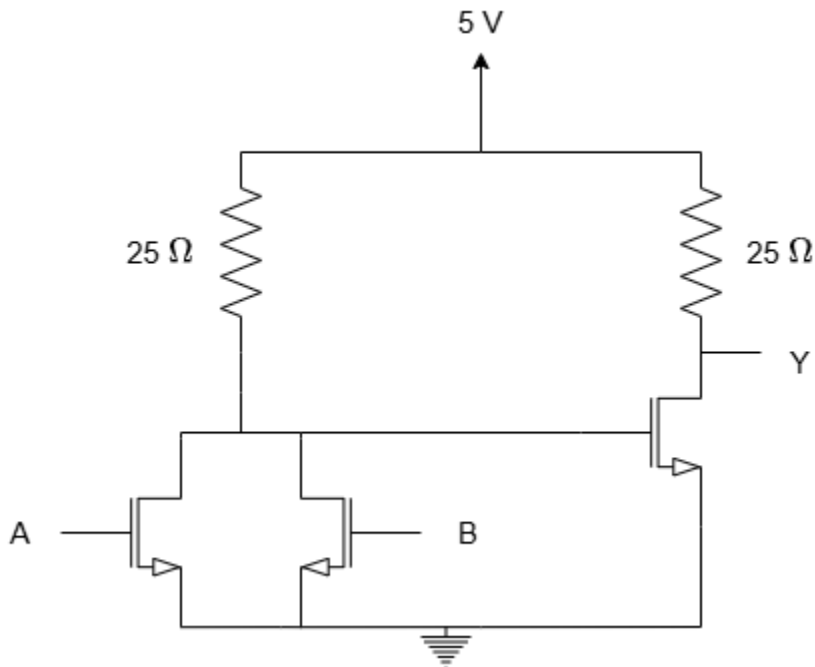
- Find the low output threshold.
- Find the average power dissipation.
- If a new NMOS is used for 'B' such that the drain currents are equal for $A=1$ & $B=1$, find its K'_{n_B} , given, $V'_{TN_B} = V_{TN_B} = 0.3\text{ V}$

$$c) 0.401 \text{ A/V}^2$$

$$b) 0.9285 \text{ W}$$

$$a) 0.063 \text{ V}$$

Exercise 3



For the given circuit-

$$V_{TN_A} = V_{TN_B} = V_{TN_Y} = 0.3 \text{ V},$$

$$K_{n_A} = K_{n_B} = K_{n_Y} = 0.5 \text{ A/V}^2$$

- What logic function does the circuit implement?
- Find the maximum power dissipation.
- What is the higher threshold of output voltage?